Spread Spectrum Clock Generator

Product Description

The PCS3P25811/12/14 devices are versatile spread spectrum frequency modulators designed specifically for a wide range of input clock frequencies from 4 MHz to 32 MHz.

The PCS3P25811/12/14 reduce electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of down stream clock and data dependent signals. It allows significant system cost savings by reducing the number of circuit board layers, ferrite beads, shielding, and other passive components that are traditionally required to pass EMI regulations.

The PCS3P25811/12/14 can generate an EMI reduced clock from crystal, ceramic resonator, or system clock.

The PCS3P25811/12/14 modulate the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation'.

The PCS3P25811/12/14 use the most efficient and optimized modulation profile approved by the FCC and is implemented in a proprietary all-digital method.

The PCS3P25811/12/14 have 2 pins S0 and S1 to control the selection of Center Spread, Down Spread and No–Spread functions. Additionally there is a 3 level logic contol FSEL, for selecting one of the three different frequency ranges within the operating frequency range. Refer *Input/Output Frequency Range Selection Table*.

The PCS3P25811/12/14 operate from a 2.8 V to 3.6 V supply and are available in 8 pin SOIC, and 8L 2 mm x 2 mm WDFN packages.

Applications

The PCS3P25811/12/14 are targeted towards EMI management in applications such as LCD Panels, MFPs, Digital copiers, Networking, PC peripheral devices, consumer electronics, and embedded controller systems.

Features

- Generates a 1x (PCS3P25811), 2x (PCS3P25812) and 4x(PCS3P25814) Low EMI Spread Spectrum Clock of the Input Frequency
- Provides up to 15 dB of EMI Suppression
- Input Frequency: 4 MHz 32 MHz
- Output Frequency: PCS3P25811: 4 MHz 32 MHz PCS3P25812: 8 MHz – 64 MHz PCS3P25814: 16 MHz – 128 MHz

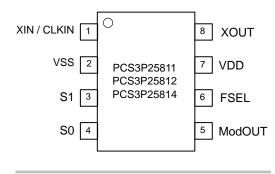


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8 1 SOIC-8 NB CASE 751 WDFN8 2x2, 0.5P CASE 511AQ





ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

- Selectable Spread Options: Down Spread and Center Spread
- Low Power Dissipation: 3.3 V: 20 mW (typ) @ 6 MHz
 3.3 V: 24 mW (typ) @ 12 MHz
 3.3 V: 30 mW (typ) @ 24 MHz
- Low Inherent Cycle-to-Cycle Jitter
- Supply Voltage: 2.8 V to 3.6 V
- LVCMOS Input and Output
- Functional and Pinout Compatible to Cypress CY25811, CY25812 and CY25814
- 8-pin SOIC, and 8L 2 mm x 2 mm WDFN (TDFN) Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

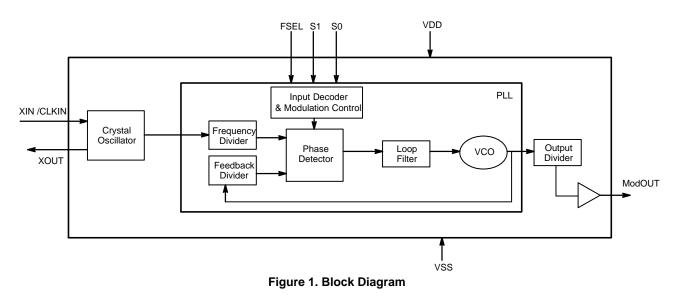


Table 1. PIN DESCRIPTION

Pin #	Pin Name	Туре	Description
1	XIN / CLKIN	Input	Crystal connection or External Clock input.
2	VSS	Power	Ground to entire chip.
3	S1	Input	Digital 3 level logic input (1–M–0) used to select Center, Down and No spread options. (Refer to <i>Frequency Deviation Selection Table).</i> Default = M.
4	SO	Input	Digital 3 level logic input (1–M–0) used to select Center, Down and No spread options. (Refer to <i>Frequency Deviation Selection Table).</i> Default = M.
5	ModOUT	Output	Spread Spectrum Clock Output.
6	FSEL	Input	Frequency range select. Digital 3 level logic input (1–M–0) used to select Input Clock frequency range (Refer to <i>Input/Output Frequency Range Selection Table</i>). Default = M.
7	VDD	Power	Power supply for the entire chip (2.8 V to 3.6 V).
8	XOUT	Output	Crystal connection. If using an external reference, this pin must be left unconnected.

Table 2. OUTPUT FREQUENCY RANGE SELECTION

	PCS3P25811 (1x)		PCS3P25812 (2x)		PCS3P25814 (4x)		
FSEL (pin 6)	Input (MHz)	Output (MHz)	Input (MHz)	Output (MHz)	Input (MHz)	Output (MHz)	Modulation Rate
0	4 – 8	4 – 8	4 – 8	8 – 16	4 – 8	16 – 32	Input Frequency / 128
1	8 – 16	8 – 16	8 – 16	16 – 32	8 – 16	32 – 64	Input Frequency / 256
М	16 – 32	16 – 32	16 – 32	32 – 64	16 – 32	64 – 128	Input Frequency / 512

		S1 = 0 S0 = 0	S1 = 0 S0 = M	S1 = 0 S0 = 1	S1 = M S0 = 0	S1 = 1 S0 = 1	S1 = 1 S0 = 0	S1 = M S0 = 1	S1 = 1 S0 = M	S1 = M S0 = M
CLKIN (MHz)	FSEL	Center	Center	Center	Center	Down	Down	Down	Down	No Spread
4 – 5	0	±1.4	±1.2	±0.6	±0.5	-3	-2.2	-1.9	-0.7	0
5 – 6	0	±1.3	±1.1	±0.5	±0.4	-2.7	-1.9	-1.7	-0.6	0
6 – 7	0	±1.2	±0.9	±0.5	±0.4	-2.5	-1.8	-1.5	-0.6	0
7 – 8	0	±1.1	±0.9	±0.4	±0.3	-2.3	-1.7	-1.4	-0.5	0
8 – 10	1	±1.4	±1.2	±0.6	±0.5	-3	-2.2	-1.9	-0.7	0
10 – 12	1	±1.3	±1.1	±0.5	±0.4	-2.7	-1.9	-1.7	-0.6	0
12 – 14	1	±1.2	±0.9	±0.5	±0.4	-2.5	-1.8	-1.5	-0.6	0
14 – 16	1	±1.1	±0.9	±0.4	±0.3	-2.3	-1.7	-1.4	-0.5	0
16 – 20	М	±1.4	±1.2	±0.6	±0.5	-3	-2.2	-1.9	-0.7	0
20 – 24	М	±1.3	±1.1	±0.5	±0.4	-2.7	-1.9	-1.7	-0.6	0
24 – 28	М	±1.2	±0.9	±0.5	±0.4	-2.5	-1.8	-1.5	-0.6	0
28 – 32	М	±1.1	±0.9	±0.4	±0.3	-2.3	-1.7	-1.4	-0.5	0

Table 3. OUTPUT FREQUENCY DEVIATION SELECTION

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

3 Level Digital Logic

S0, S1, and FSEL digital inputs are designed to sense 3 different logic levels designated as High "1", Low "0" and Middle "M". With this 3–Level digital input logic 9 different logic states can be detected.

S0, S1 and FSEL pins include an on chip 100 K (50 K / 50 K) resistor divider. No external application resistors are needed to implement the 3–Level logic levels as shown in table on the right:

Logic	Control Pins	
1	FSEL, S0, S1 to VDD	
М	FSEL, S0, S1 UNCONNECTED	
0	FSEL, S0, S1 to VSS] ↓vss

Table 4. OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{DD} , V _{IN}	Voltage on any pin with respect to VSS	2.8	3.6	V
T _A	Operating temperature	0	+70	°C
CL	Load Capacitance		15	pF
C _{IN}	Input Capacitance		7	pF

Table 5. ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Rating	Unit
V _{DD} , V _{IN}	Voltage on any pin with respect to Ground	-0.5 to +4.6	V
T _{STG}	Storage temperature	-65 to +125	°C
Ts	Max. Soldering Temperature (10 sec)	260	°C
TJ	Junction Temperature	150	°C
T _{DV}	Static Discharge Voltage (As per JEDEC STD 22– A114–B)	2	KV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Symbol		Parameter	Min	Тур	Max	Units		
VDD	Supply Voltage			2.8	3.3	3.6	V	
V _{IL}	Input low voltage	Commercial Ter	mperature	0		0.15 V _{DD}	V	
	(S0, S1, FSEL Inputs)	Industrial Temp	erature	0		0.13 V _{DD}	-	
V _{IM}	Input middle voltage (S0,	S1, FSEL Inputs)		0.4 VDD		0.60 V _{DD}	V	
V _{IH}	Input high voltage (S0, S1	, FSEL Inputs)		0.85 VDD		V _{DD}	V	
V _{OL} Output low voltage	I _{OL} = 4 mA				0.4	V		
	(ModOUT Output)	I _{OL} = 10 mA				1.2		
V _{OH} Output high voltage (ModOUT Output)		$I_{OH} = -4 \text{ mA}$		2.4			V	
	(ModOUT Output)	I _{OH} = -6 mA	2					
C _{IN}	Input Capacitance (XIN a	nd XOUT)		6		9	pF	
I _{DD}	Dynamic supply current	Commercial	XIN / CLKIN = 12 MHz			8	mA	
	(Unloaded Output)	Temperature	XIN / CLKIN = 24 MHz			10		
			XIN / CLKIN = 32 MHz			13		
		Industrial	XIN / CLKIN = 12 MHz			10	mA	
	Iemperature	Temperature	XIN / CLKIN = 24 MHz		12			
			XIN / CLKIN = 32 MHz			15	1	
I _{CC}	Static supply current (XIN	/ CLKIN pulled to	VSS)			0.5	mA	

Table 6. DC ELECTRICAL CHARACTERISTICS

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

Table 7. AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter			Тур	Max	Units
f _{IN}	Input Clock frequency for PCS3	P25811/12/14	4		32	MHz
fout	ModOUT Clock frequency for P	CS3P25811	4		32	MHz
	ModOUT Clock frequency for P	8		64		
	ModOUT Clock frequency for P	16		128		
t _{LH}	ModOUT Rise time (Measured from 20% to 80%)	PCS3P25811/12/14	2		5	nS
(Notes 1, 2)		PCS3P25814 when FSEL = M	1		2.2	
t _{HL}	ModOUT Fall time	PCS3P25811/12/14	2		4.4	nS
(Notes 1, 2)	(Measured from 80% to 20%)	PCS3P25814 when FSEL = M	1		2.2	
T _{DCIN}	Input Clock Duty Cycle (XIN / CLKIN)		40		60	%
T _{DCOUT} (Notes 1, 2)	Output Clock Duty Cycle (ModOUT)		40		60	%

Parameters are specified with 15 pF loaded outputs.
 Parameter is guaranteed by design and characterization. Not 100% tested in production.

Table 7. AC ELECTRICAL CHARACTERISTICS

Symbol	Pa	rameter		Min	Тур	Max	Units
TJC	Cy–Cy Jitter,					600	pS
(Note 2)	for ModOUT with Spread ON		8 MHz			450	
	(for Commercial temperature)	PCS3P25812	16 MHz			400	
			32 MHz			380	
		PCS3P25814	64 MHz			380	
			128 MHz			380	
	Cy–Cy Jitter,	PCS3P25811	CLKIN = 6 MHz			500	pS
	for ModOUT with Spread ON	PCS3P25812 PCS3P25814	CLKIN = 12 MHz			400	
	(for Industrial temperature)		CLKIN = 24 MHz			380	
t _{ON} (Note 2)	PLL Lock Time (Stable power supply, valid	Commercial Temperature Industrial Temperature				2	mS
	input clock to valid Clock on ModOUT)					3	

1. Parameters are specified with 15 pF loaded outputs.

2. Parameter is guaranteed by design and characterization. Not 100% tested in production.

Application Schematic

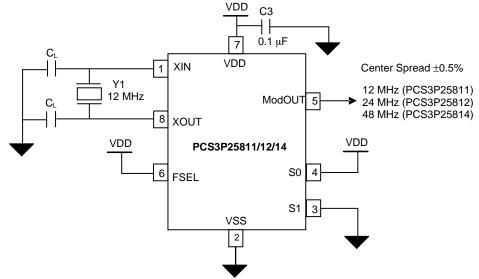
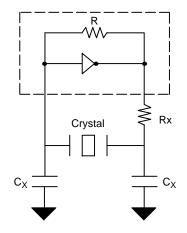


Figure 2. Application Schematic

Table 8. TYPICAL CRYSTAL SPECIFICATIONS

Fundamental AT Cut Parallel Resonant Crystal						
Nominal frequency	12 MHz					
Frequency tolerance	±30 ppm or better at 25°C					
Operating temperature range	-25°C to +85°C					
Storage temperature	-40°C to +85°C					
Load capacitance	18 pF					
Shunt capacitance	7 pF maximum					
ESR	25 Ω					

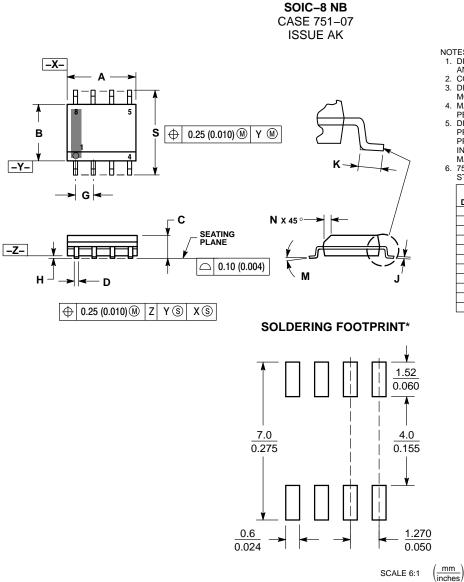
NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.



 $\begin{array}{l} C_X = 2^*(C_P-C_S), \\ \text{Where } C_P = \text{Load capacitance of crystal.} \\ C_S = \text{Stray capacitance due to } C_{\text{IN}}, \text{PCB}, \text{Trace, etc.} \end{array}$

Figure 3. Typical Crystal Interface Circuit

PACKAGE DIMENSIONS

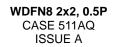


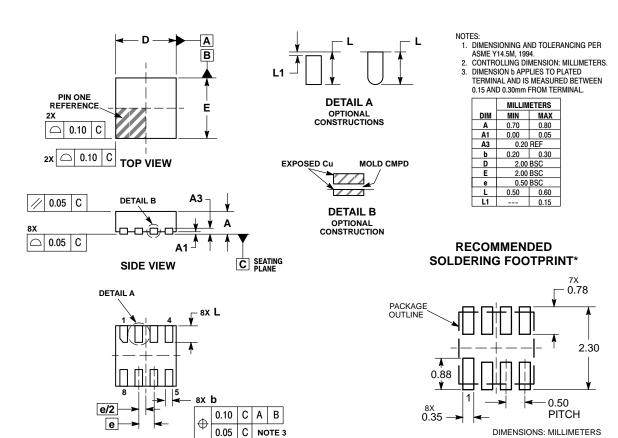
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

- NOTES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
 751–01 THRU 751–06 ARE OBSOLETE. NEW
- 751–01 THRU 751–06 ARE OBSOLETE. NEW STANDARD IS 751–07.

	MILLIN	IETERS	INCHES					
DIM	MIN	MAX	MIN	MAX				
Α	4.80	5.00	0.189	0.197				
в	3.80	4.00	0.150	0.157				
С	1.35	1.75	0.053	0.069				
D	0.33	0.51	0.013	0.020				
G	1.27	7 BSC	0.050 BSC					
н	0.10	0.25	0.004	0.010				
J	0.19	0.25	0.007	0.010				
Κ	0.40	1.27	0.016	0.050				
Μ	0 °	8 °	0 °	8 °				
Ν	0.25	0.50	0.010	0.020				
S	5.80	6.20	0.228	0.244				

PACKAGE DIMENSIONS





BOTTOM VIEW

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Table 9. ORDERING INFORMATION

Part Number Markin		Package Type	Temperature	
PCS3P25811AG08SR	CGL	8-pin SOIC - Tape & Reel, Green	0°C to +70°C	
P3P25812AG-08SR	CIL	8-pin SOIC - Tape & Reel, Green	0°C to +70°C	
P3P25814AG-08SR	CKL	8-pin SOIC - Tape & Reel, Green	0°C to +70°C	
P3P25811AG-08CR	CG	8L–WDFN (2 mm x 2 mm) – Tape & Reel, Green	0°C to +70°C	
P3P25812AG-08CR	CI	8L–WDFN (2 mm x 2 mm) – Tape & Reel, Green	0°C to +70°C	
P3P25814AG-08CR	СК	8L–WDFN (2 mm x 2 mm) – Tape & Reel, Green	0°C to +70°C	

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

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